TOSHIBA Photocoupler GaAs IRED & Photo-MOS FET

TLP200D

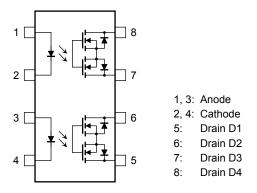
PBX Modem • Fax Card Measurement Instrument

The TOSHIBA TLP200D consists of gallium arsenide infrared emitting diode optically coupled to a photo-MOS FET in an 8-pin SOP.

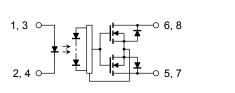
The TLP200D is a 2-form-A switch which is suitable for replacement of mechanical relays in many applications which require space savings.

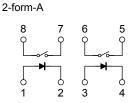
- SOP 8 pin (2.54SOP8): 2-form-A
- Peak off-state voltage: 200 V (min)
- Trigger LED current: 3 mA (max)
- On-state current: 200 mA (max)
- On-state resistance: 8Ω (max)
- Isolation voltage: 1500 Vrms (min)
- UL recognized: UL1577, file No. E67349

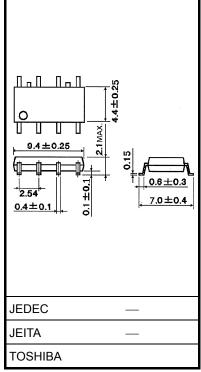
Pin Configurations (top view)



Schematic







Weight: 0.2 g (typ.)

Unit: mm

Absolute Maximum Ratings (Ta = 25°C)

| Characteristics | | Symbol | Rating | Unit | |
|--|--|----------------------|------------|-------|--|
| LED | Forward current | ١ _F | 50 | mA | |
| | Forward current derating $(Ta \ge 25^{\circ}C)$ | ∆I _F /°C | -0.5 | mA/°C | |
| | Pulse forward current (100 μs pulse, 100 pps) | I _{FP} | 1 | А | |
| | Reverse voltage | V _R | 5 | V | |
| | Junction temperature | Tj | 125 | °C | |
| Detector | Off-state output terminal voltage | V _{OFF} | 200 | V | |
| | On-state current | I _{ON} | 200 | mA | |
| | On-state RMS current derating $(Ta \ge 25^{\circ}C)$ | ∆l _{ON} /°C | -2.0 | mA/°C | |
| | Junction temperature | Tj | 125 | °C | |
| Storage temperature range | | T _{stg} | -55 to 125 | °C | |
| Operating temperature range | | T _{opr} | -40 to 85 | °C | |
| Lead soldering temperature (10 s) | | T _{sol} | 260 | °C | |
| Isolation voltage (AC, 1 min., R.H. \leq 60%) (Note 1) | | BVS | 1500 | Vrms | |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 1: Device considered a two-terminal device: Pins 1, 2, 3 and 4 shorted together and pins 5, 6, 7 and 8 shorted together.
- Note 2: Two channels operating simultaneously.

Recommended Operating Conditions

| Characteristics | Symbol | Min | Тур. | Max | Unit |
|-----------------------|------------------|-----|------|-----|------|
| Supply voltage | V _{DD} | | 150 | 200 | V |
| Forward current | ١ _F | 5 | 7.5 | 25 | mA |
| On-state current | I _{ON} | | | 130 | mA |
| Operating temperature | T _{opr} | -20 | | 65 | °C |

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Individual Electrical Characteristics (Ta = 25°C)

| | Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|----------|-------------------|------------------|--------------------------|-----|------|-----|------|
| LED | Forward voltage | VF | I _F = 10 mA | 1.0 | 1.15 | 1.3 | V |
| | Reverse current | Ι _R | V _R = 5 V | _ | _ | 10 | μA |
| | Capacitance | CT | V = 0, f = 1 MHz | _ | 30 | _ | pF |
| Detector | Off-state current | IOFF | V _{OFF} = 200 V | _ | _ | 1 | μA |
| | Capacitance | C _{OFF} | V = 0, f = 1 MHz | | 100 | | pF |

Coupled Electrical Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---------------------|-----------------|---|-----|------|-----|------|
| Trigger LED current | I _{FT} | I _{ON} = 200 mA | _ | 1 | 3 | mA |
| On-state resistance | R _{ON} | $I_{ON} = 200 \text{ mA}, I_F = 5 \text{ mA}$ | _ | 5 | 8 | Ω |

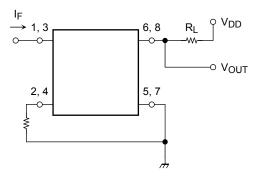
Isolation Characteristics (Ta = 25°C)

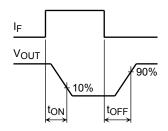
| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|-----------------------------|----------------|----------------------------|-------------------------|------------------|-----|-------|
| Capacitance input to output | CS | $V_{S} = 0, f = 1 MHz$ | _ | 0.8 | _ | pF |
| Isolation resistance | R _S | $V_S=500~V,~R.H.\leq 60\%$ | 5 × 10 ¹⁰ | 10 ¹⁴ | | Ω |
| Isolation voltage | BVS | AC, 1 minute | 1500 | _ | _ | Vrms |
| | | AC, 1 s, in oil | _ | 3000 | _ | VIIIS |
| | | DC, 1 minute, in oil | | 3000 | | Vdc |

Switching Characteristics (Ta = 25°C)

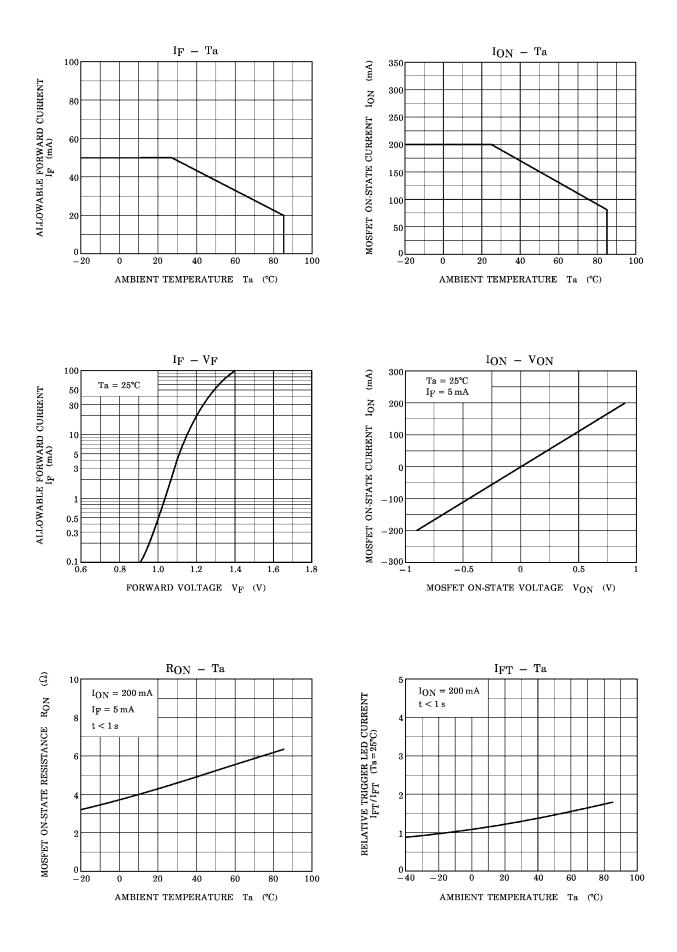
| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|-----------------|-----------------|--|------|------|-----|------|
| Turn-on time | t _{ON} | $R_L = 200 \Omega$ (Not | e) — | 0.6 | 1.5 | ms |
| Turn-off time | tOFF | $V_{DD} = 20 \text{ V}, \text{ I}_{\text{F}} = 5 \text{ mA}$ | | 0.1 | 1.0 | ms |

Note: Switching time test circuit

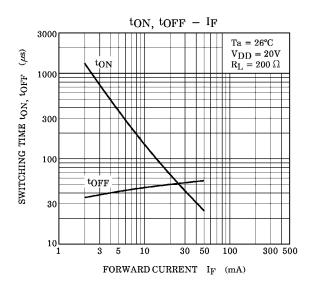


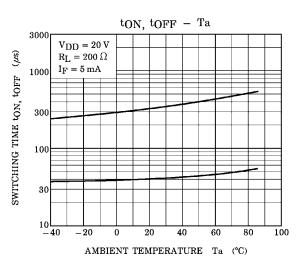


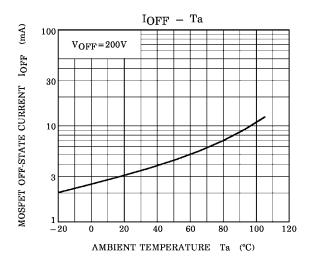
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